Commercial Poly-Silicon Specifications

- Here are the specification for poly-silicon from one of the worlds largest suppliers, Wacker Siltronic as they appear in the Internet in Nov. 2000.
 - Notice: The "w" or "a" behind the concentration denotes weigth or atomic parts per m = million, b = billion, t = trillion.

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PolySilicon for Crucible Grow	ving		
Chip Size		mm	5 - 45 / 20 - 65 / 20 - 150
Surface			smooth, etched
Surface Metal Concentration	Monitor: Iron	pptw	< 500
Bulk Element Concentration	Donors (P, As, Sb)	ppta	< 150
	Acceptors (B, Al)	ppta	< 50
	Carbon	ppba	< 100
PolySilicon Ingots for Float Z	one Growing		
Ingot Length		mm	600 -1,850
Diameter		mm	90 - 105 / 118 - 135 / 135 - 154
Surface			smooth, etched
Bulk Element Concentration	Donors (P, As, Sb)	ppta	< 300
	Acceptors (B, Al)	ppta	< 100
	Carbon	ppba	< 200
PolySilicon Ingots for Crucibl	le Growing		
Ingot Length		mm	320 - 980
Diameter		mm	90 - 115 / 115 - 135
Surface			smooth, etched
Bulk Element Concentration	Donors (P, As, Sb)	ppta	< 300
	Acceptors (B, Al)	ppta	< 100
	Carbon	ppba	< 200
Solar Grade PolySilicon for C	rucible Growing/Casting		
Chip Size		mm	0 - 15 / 5 - 160
Bulk Element Concentration	Donors (P, As, Sb)	ppta	< 300
	Acceptors (B, Al)	ppta	< 100
	Carbon	ppba	< 200

Here some production information:

- According to "Solid State Technology" July 2005, the production numbers are as follows:
 - Total production 2005: 26.000.000 kg; about 2/3 for microelectronics, 1/3 for photovoltaics.
 - Expected production 2006: 29.000.000 kg.
- Right now (end of 2007) there is a tremendous shortage of poly Si because the solar cell industry grows so fast, that poly Si production cannot keep pace, see also the <u>link</u>.
- Expected shortfalls:
 - 2005: 4.000.000 kg
 - 2006: 6.000.000 kg.
 - 2007: 12.000.000 kg.
 - 2008: 20.000.000 kg.
- The expected shortfalls result to a large extent from a growth growthraterate of 40 % for photovoltaics and from technical and financial difficulties to crank up production at a high rate. However, alternative processes for solar Si production are expected to come on-line in 2006..